



PRODUCT NAME : BF256 N-Channel RF Transistor (Pack of 5)

PRICE : Rs 49.00

SKU : RM1765



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DESCRIPTION

The metal–oxide–semiconductor field-effect transistor is a type of transistor used for amplifying or switching electronic signals.

Features of BF256 N-Channel RF Transistor:

- Drain-Gate Voltage (V_{dg}): 30V.
- Gate-Source Voltage (V_{gs}): 30V.
- Gate-Source Voltage (V_{gs-off}): 8V.
- Drain Current (I_{dss}): 18mA.
- Power Dissipation (P_{tot}): 350mW.
- Type: N-Channel.

Applications of BF256 N-Channel RF Transistor:

- It is used in switching device.
- It is used in amplifying device.
- It is used in DIY kits.
- FM Radio.
- It is used in Electronic projects.

Also Searched as : **N channel MOSFET, BF256 MOSFET.**